

ISC Silicon PNP Power Transistor

DESCRIPTION

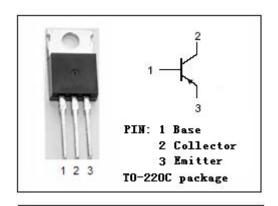
- · Collector-Emitter BreakdownVoltage-
 - : V_{(BR)CEO}= -60V(Min.)
- · Low Collector Saturation Voltage-
 - : V_{CE(sat)}= -1.0(Max.) @I_C= -2A
- · Wide area of safe operation
- Good Linearity of h_{FE}
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

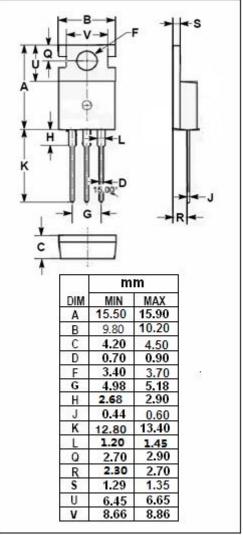
APPLICATIONS

• Designed for power amplifier and switching applications .

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	-60	V
V _{CEO}	Collector-Emitter Voltage	-60	V
V _{EBO}	Emitter-Base Voltage	-6	V
Ic	Collector Current-Continuous	-4	Α
I _{CM}	Collector Current-Peak	-6	А
Pc	Collector Power Dissipation@Tc=25°C	40	W
TJ	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature	-55~150	







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2SB901

ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _(BR) CEO	Collector-Emitter Breakdown Voltage	Ic= -1mA; I _B = 0	-60			V
V _{(BR)CBO}	Collector-Base breakdown voltage	I _C =-1mA; I _E = 0	-60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -1mA; I _C = 0	-6			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -2A; I _B = -0.2A			-1.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C =- 2A; V _{CE} =-4V			-1.4	V
Ісво	Collector Cutoff Current	V _{CB} = -60V; I _E = 0			-100	μА
I _{CEO}	Collector Cutoff Current	V _{CE} = -60V; I _B = 0			-100	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-10	μА
h _{FE}	DC Current Gain	Ic= -1A; VcE= -4V	40		200	
f _T	Current-Gain—Bandwidth Product	I _C =-0.5A ; V _{CE} = -10V	6			MHz

Notice:

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